

Three-Output Low Power MEMS Clock Generator

Features

- MEMS-Based Clock Generator Eliminates the Need for External Crystal or Reference Clock
- Three LVCMOS Output Clocks: 2 kHz to 100 MHz
- Low Power Consumption: 5.2 mA (All Outputs Active)
- · Wide Supply Voltage Range: 1.71V to 3.63V
- · Ultra-Small Package Sizes:
 - 1.6 mm x 1.2 mm
 - 2.0 mm x 1.6 mm
 - 2.5 mm x 2.0 mm
- High Frequency Stability: ±20 ppm, ±25 ppm, ±50 ppm
- · Wide Temperature Range:

Automotive: -40°C to +125°C
 Ext. Industrial: -40°C to +105°C

Industrial: -40°C to +85°C
 Commercial: -20°C to +70°C

- · Excellent Shock and Vibration Immunity:
 - Shock: Qualified to MIL-STD-883E Method 2002.3, Test Condition G (30,000g)
 - Vibration: Qualified to MIL-STD-883E Method 2007.2, Test Condition C (70g)
- · High Reliability
- · Lead-Free and RoHS-Compliant
- Automotive Option AEC-Q100 Available

Applications

- Low Power/Portable Applications: IoT, Embedded/Smart Devices
- Consumer: Home Healthcare, Fitness Devices, Home Automation
- Industrial: Building/Factory Automation, Surveillance Cameras

General Description

The DSC613 is a MEMS low power, ultra-small footprint, crystal-less family of clock generators. The DSC613 family is factory-configurable and generates up to three LVCMOS outputs from two PLLs. Each output can be configured to generate frequencies from 2 kHz to 100 MHz.

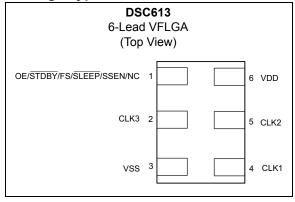
The DSC613 implements Microchip's proven PureSilicon™ MEMS technology to provide low jitter and high stability across a wide range of supply voltages and temperatures. By eliminating the external quartz crystal, Microchip's crystal-less™ clock generators significantly enhance reliability and accelerate product development.

The DSC613 has one control input that can be configured to function as output enable/disable, standby, sleep, spread spectrum enable, and frequency select. The DSC613 is available in space saving 6-pin, 1.6 mm x 1.2 mm, 2.0 mm x 1.6 mm, and 2.5 mm x 2.0 mm VFLGA plastic packages.

The DSC613 spread spectrum function includes both center and down spreading, and is explained further in the Spread Spectrum section.

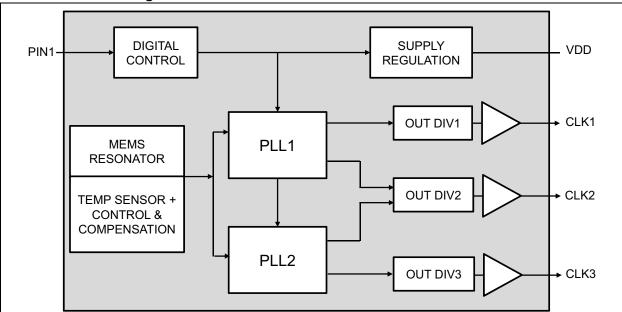
The DSC613 is a highly configurable device and is factory programmed to meet the customer's needs. Microchip's ClockWorks Configurator must be used to choose the necessary options, create the final part number, data sheet, and order samples.

Package Type



DSC613

Functional Block Diagram



1.0 ELECTRICAL CHARACTERISTICS

Absolute Maximum Ratings †

Supply Voltage	
Input Voltage	–0.3V to V _{DD} + 0.3V
ESD Protection (HBM)	4 kV
ESD Protection (MM)	400V
ESD Protection (CDM)	2 kV

† Notice: Stresses above those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress rating only and functional operation of the device at those or any other conditions above those indicated in the operational sections of this specification is not intended. Exposure to maximum rating conditions for extended periods may affect device reliability.

TABLE 1-1: ELECTRICAL CHARACTERISTICS

Electrical Characteristics: V_{DD} = 1.8V ±5% to 3.3V ±10%; T_A = -40°C to +125°C, unless noted.

Parameter	Symbol	Min.	Тур.	Max.	Units	Conditions
Supply Voltage	V_{DD}	1.71	_	3.63	V	Note 1
Active Supply Current	I _{DD}	_	5.2	6.5	mA	$\begin{split} &f_{\text{CLK1}} = 24 \text{ MHz, } f_{\text{CLK2}} = 27 \text{ MHz,} \\ &f_{\text{CLK3}} = 12 \text{ MHz, } V_{\text{DD}} = 1.8 \text{V, No} \\ &\text{Load} \end{split}$
Active Supply Current (Sleep Mode, 1 PLL Off)	I _{DDSL}	-	3	_	mA	CLK2 = SLEEP, f_{CLK1} = 25 MHz, V_{DD} = 1.8V, No Load
Active Supply Current (32.768 kHz Output Only)	I _{DD32k}		1.4	_	mA	f_{CLK3} = 32.768 kHz, V_{DD} = 1.8V, No Load
Standby Supply Current,		_	1.0	_		V _{DD} = 1.8V/2.5V
Note 2	ISTDBY		1.5	_	μA	V _{DD} = 3.3V
				±20		
Frequency Stability, Note 3	Δf			±25	ppm	All temperature ranges
				±50		
Aging	Δf	_	_	±5	nnm	1st year @ +25°C
Aging	Ді	_	_	±1	ppm	Per year after the first year
Startup Time	t _{SU}	_	_	1.5	ms	From 90% V _{DD} to valid clock output, T = +25°C
lanut Lagia Lavala Neta 4	V _{IH}	0.7 x V _{DD}	_	_	.,	Input logic high
Input Logic Levels, Note 4	V _{IL}	_	_	0.3 x V _{DD}	V	Input logic low
Output Disable Time	t _{DA}	_	_	200 + 2 Periods	ns	Note 5
Output Enable Time	t _{EN}	_	1.0	_	μs	Note 6
Enable Pull-Up Resistor	_	_	300	_	kΩ	If configured. Note 7
	V _{OHY}	0.8 x V _{DD}	_	_		I = 6 mA (high drive) or I = 3 mA (standard drive)
Output Logic Levels	V _{OLY}		_	0.2 x V _{DD}	V	I = -6 mA (high drive) or I = -3 mA (standard drive)
Output Logic Levels	V _{OHX}	0.8 x V _{DD}	_	_	V	I = 1 mA (low drive)
	V _{OLX}	_	_	0.2 x V _{DD}		I = -1 mA (low drive)

DSC613

TABLE 1-1: ELECTRICAL CHARACTERISTICS (CONTINUED)

Electrical Characteristics: V_{DD} = 1.8V ±5% to 3.3V ±10%; T_A = -40°C to +125°C, unless noted.

Parameter	Symbol	Min.	Тур.	Max.	Units	Conditions
			1.2	2.0		V _{DD} = 1.8V, Standard drive 20% - 80% C _L = 10 pF (CLK1/CLK2)
	t _{RY1} /t _{FY1}	l	0.6	1.2		$V_{\rm DD}$ = 2.5V/3.3V, Standard drive 20% - 80% $C_{\rm L}$ = 10 pF (CLK1/CLK2)
Output Transition Time, Rise Time/Fall Time	+ /+	l	1.0	1.5	ns	V _{DD} = 1.8V, High drive 20% - 80% C _L = 15 pF (CLK1/CLK2)
Time/Faii Time	t _{RY2} /t _{FY2}		0.5	1.0		V _{DD} = 2.5V/3.3V, High drive 20% - 80% C _L = 15 pF (CLK1/CLK2)
	t/t		2.5	3.5		V _{DD} = 1.8V, Low drive 20% - 80% C _L = 5 pF (CLK3)
	t _{RX} /t _{FX}	l	1.5	2.2		V _{DD} = 2.5V/3.3V, Low drive 20% - 80% C _L = 5 pF (CLK3)
Frequency	f0	0.002		100	MHz	Note 8
Output Duty Cycle	SYM	45	_	55	%	_
	J _{PER}	_	20	_		f _{CLK1} = 24 MHz, f _{CLK2} = 27 MHz, f _{CLK3} = 12 MHz, V _{DD} = 1.8V
Period Jitter, RMS CLK1/CLK2		ı	14	ı	ps	f_{CLK1} = 24 MHz, f_{CLK2} = 27 MHz, f_{CLK3} = 12 MHz, V_{DD} = 3.3V
		1	10	1		f _{CLK1} = 24 MHz, f _{CLK2} = 12 MHz, f _{CLK3} = 32.768 kHz, V _{DD} = 3.3V
			170			f_{CLK1} = 24 MHz, f_{CLK2} = 27 MHz, f_{CLK3} = 12 MHz, V_{DD} = 1.8V
Period Jitter, Peak-to-Peak CLK1/CLK2	J _{PER}		140		ps	f_{CLK1} = 24 MHz, f_{CLK2} = 27 MHz, f_{CLK3} = 12 MHz, V_{DD} = 3.3V
		1	80	1		f_{CLK1} = 24 MHz, f_{CLK2} = 12 MHz, f_{CLK3} = 32.768 kHz, V_{DD} = 3.3V
		1	150	1		f_{CLK1} = 24 MHz, f_{CLK2} = 27 MHz, f_{CLK3} = 12 MHz, V_{DD} = 1.8V
Cycle-to-Cycle Jitter, Peak CLK1/CLK2	J _{CY-CY}	_	120	_	ps	f_{CLK1} = 24 MHz, f_{CLK2} = 27 MHz, f_{CLK3} = 12 MHz, V_{DD} = 3.3V
		_	70	_		f_{CLK1} = 24 MHz, f_{CLK2} = 12 MHz, f_{CLK3} = 32.768 kHz, V_{DD} = 3.3V

TABLE 1-1: ELECTRICAL CHARACTERISTICS (CONTINUED)

Electrical Characteristics: V_{DD} = 1.8V ±5% to 3.3V ±10%; T_A = -40°C to +125°C, unless noted.

Parameter	Symbol	Min.	Тур.	Max.	Units	Conditions
Period Jitter, RMS		_	40	ı	ne	f_{CLK1} = 24 MHz, f_{CLK2} = 27 MHz, f_{CLK3} = 12 MHz, V_{DD} = 1.8V
CLK3	JPER	_	35	ı	ps	f_{CLK1} = 24 MHz, f_{CLK2} = 27 MHz, f_{CLK3} = 12 MHz, V_{DD} = 3.3V
Period Jitter, Peak-to-Peak		_	270		ps	f _{CLK1} = 24 MHz, f _{CLK2} = 27 MHz, f _{CLK3} = 12 MHz, V _{DD} = 1.8V
CLK3	J _{PER}	_	220		ρs	f_{CLK1} = 24 MHz, f_{CLK2} = 27 MHz, f_{CLK3} = 12 MHz, V_{DD} = 3.3V
Cycle-to-Cycle Jitter, Peak CLK3	J _{CY-CY}	_	235		20	f_{CLK1} = 24 MHz, f_{CLK2} = 27 MHz, f_{CLK3} = 12 MHz, V_{DD} = 1.8V
		_	190		ps	f _{CLK1} = 24 MHz, f _{CLK2} = 27 MHz, f _{CLK3} = 12 MHz, V _{DD} = 3.3V

- Note 1: V_{DD} pin should be filtered with a 0.1 μF capacitor.
 - 2: Excludes pull-up current.
 - 3: Includes frequency variations due to initial tolerance, temperature, and power supply voltage.
 - 4: Input waveform must be monotonic with rise/fall time < 10 ms.
 - 5: Output disable time takes up to two Periods of the output waveform, plus 200 ns.
 - **6:** For parts configured with OE, not Standby.
 - **7:** Output is enabled if pad is floated or not connected.
 - 8: CLK3 maximum frequency is 80 MHz.

DSC613

TEMPERATURE SPECIFICATIONS (Note 1)

Parameters	Sym.	Min.	Тур.	Max.	Units	Conditions
Temperature Ranges						
Junction Operating Temperature	T_J	_	_	+150	°C	_
Storage Temperature Range	T _S	-55	_	+150	°C	_
Lead Temperature	_	_	+260	_	°C	Soldering, 40s

Note 1: The maximum allowable power dissipation is a function of ambient temperature, the maximum allowable junction temperature and the thermal resistance from junction to air (i.e., T_A, T_J, θ_{JA}). Exceeding the maximum allowable power dissipation will cause the device operating junction temperature to exceed the maximum +150°C rating. Sustained junction temperatures above +150°C can impact the device reliability.

2.0 PIN DESCRIPTIONS

The DSC613 is a highly configurable device and can be factory programmed in many different ways to meet the customer's needs. Microchip's ClockWorks Configurator http://clockworks.microchip.com/Timing/ must be used to choose the necessary options, create the final part number, data sheet, and order samples. The descriptions of the pins are listed in Table 2-1.

TABLE 2-1: DSC613 PIN FUNCTION TABLE

Pin Number	Pin Name	Description
	OE	Output Enable: H = Active, L = Disabled (High Impedance).
	STDBY	Standby: H = Device is active, L = Device is in standby (Low Power Mode).
1	FS	Frequency Select: H = Output Frequency 1, L = Output Frequency 2.
	SLEEP	Sleep: H= Output Enabled, L= Output and associated PLL Disabled.
	SSEN	Spread Spectrum: H = Enabled, L = Disabled.
2	CLK3	Factory configurable LVCMOS clock output 3: 2 kHz to 80 MHz, low drive.
3	VSS	Ground.
4	CLK1	Factory configurable LVCMOS clock output 1: 1 MHz to 100 MHz, standard drive or high drive.
5	CLK2	Factory configurable LVCMOS clock output 2: 1 MHz to 100 MHz, standard drive or high drive.
6	VDD	Power Supply: 1.71V to 3.63V.

An explanation of the different options listed in Table 2-1 follows.

2.1 Pin 1

This is a control pin and may be configured to fulfill one of six different functions. If not actively driven, a 10 k Ω pull-up resistor is recommended.

2.1.1 OUTPUT ENABLE (OE)

Pin 1 may be configured as OE. Any combination of outputs may be turned on and off according to the state of this pin (one, two, or all three outputs).

2.1.2 STANDBY

Pin 1 may be configured as Standby. When the pin is low, all outputs will be off and the device will enter a low power mode.

2.1.3 SLEEP

Pin 1 may be configured as Sleep. When the pin is low, one phase locked loop (PLL) will shut down, enabling power saving. Any outputs driven by that PLL will be turned off.

2.1.4 SPREAD SPECTRUM ENABLE (SSEN)

Pin 1 may be configured as Spread Spectrum Enable. When the pin is high, the associated output will be spread in frequency. When low, no spreading will occur.

2.1.5 FREQUENCY SELECT (FS)

Pin 1 may be configured as FS. Each output may be set to one of two pre-programmed frequencies (six pre-programmed frequencies in all).

2.1.6 NC

Pin 1 may be configured as NC. In this case, the pin is non-functional, and the device is programmed and fixed according to the choices in ClockWorks Configurator.

2.2 Pins 2 though 6

Pins 3 and 6 are the supply terminals, V_{SS} and V_{DD} respectively. Pins 2, 4, and 5 are the three clock outputs, CLK3, CLK1, and CLK2 respectively. CLK1 and CLK2 outputs are programmable to Standard and High Drive strengths settings. CLK3 is a fixed strength, low drive output. Visit ClockWorks Configurator to customize your device.

3.0 SPREAD SPECTRUM

Spread spectrum is a slow modulation of the clock frequency over time. The PLL inside the MEMS oscillator is modulated with a triangular wave at 33 kHz. With such a slow modulation, the peak spectral energy of both the fundamental and all the harmonics is spread over a wider frequency range. This significantly reduces peak energy density, thus providing an EMI reduction. The triangular wave is chosen because of its flat spectral density.

The DSC613 MEMS oscillator family offers several modulation options: the spreading is either center spread or down spread with respect to the clock frequency. Center spreading ranges from $\pm 0.25\%$ to $\pm 2.5\%$, while down spreading ranges from $\pm 0.25\%$ to $\pm 3\%$.

If the clock frequency is 100 MHz and center spreading with $\pm 1\%$ is chosen, the output clock will range from 99 MHz to 101 MHz. If down spreading with -2% is chosen, the output clock will range from 98 MHz to 100 MHz.

Figure 3-1 and Figure 3-2 show a spectrum example of the DSC613 with a 33.333 MHz clock, modulated with central spread of ±1%.

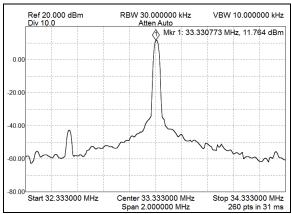


FIGURE 3-1: DSC613 Spectrum at 33.333 MHz with Modulation Turned Off.

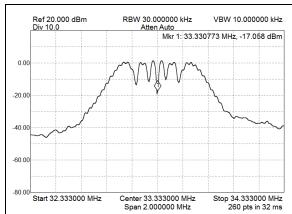


FIGURE 3-2: DSC613 Spectrum at 33.333 MHz with Modulation Turned On.

It is noticeable that the spread spectrum provides a reduction of about 10 dB from the peak power. Such a reduction may also be estimated by the following equation:

EQUATION 3-1:

 $EMI \ {\bf Reduction} = 10 \times Log \ 10 (|S| \times fc \div RBW)$ Where: $S \quad {\bf Peak-to-peak \ spread \ percentage \ (0.01, \\ this \ example)}.$ $fc \quad {\bf Carrier \ frequency \ (33.333 \ MHz, this \\ example)}.$ ${\bf RBW} \quad {\bf Resolution \ bandwidth \ of \ the \ spectrum \\ analyzer \ (30 \ kHz, this \ example)}.$

The theoretical calculation for this example provides 10.45 dB, which is consistent with the measurement.

Similarly to the fundamental frequency, all the harmonics are spread and attenuated in similar fashion. Figure 3-3 shows how the DSC613 fundamental at 33.333 MHz and its odd harmonics are attenuated when various types of modulations are selected. For picture clarity, only the center spread options are shown. However, down spread with corresponding percentage provides the same level of harmonic attenuation (e.g. central spread of $\pm 1\%$ provides the same harmonics attenuation of down spread with -2%).

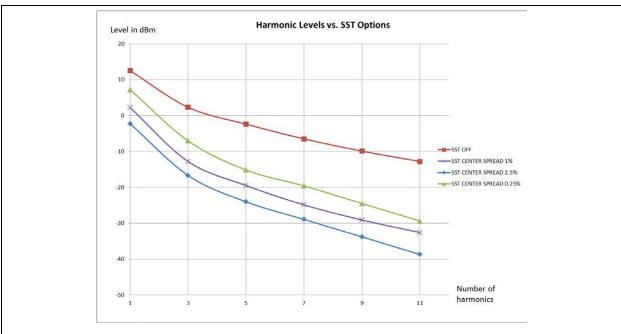


FIGURE 3-3: DSC613 Harmonic Levels with Various Spread Spectrum Options.

Visit Microchip's ClockWorks Configurator to select Spread Spectrum options.

4.0 OUTPUT WAVEFORM

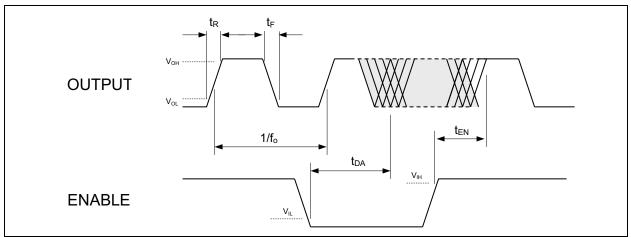


FIGURE 4-1: DSC613 Output Waveform.

5.0 BOARD LAYOUT

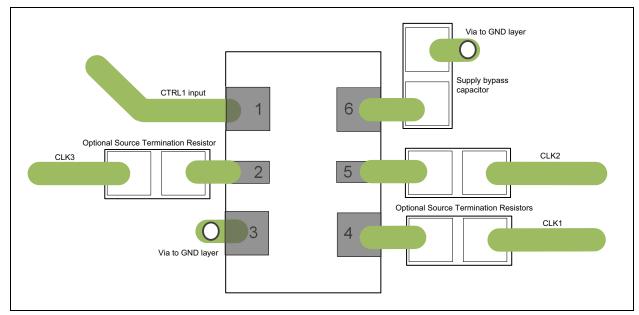


FIGURE 5-1: DSC613 Board Layout.

6.0 SOLDER REFLOW PROFILE

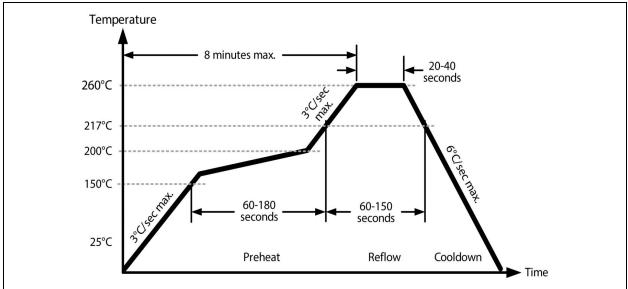


FIGURE 6-1: Solder Reflow Profile.

TABLE 6-1: SOLDER REFLOW

MSL 1 @ 260°C Refer to JSTD-020C						
Ramp-Up Rate (200°C to Peak Temp.)	3°C/sec. max.					
Preheat Time 150°C to 200°C	60 to 180 sec.					
Time Maintained above 217°C	60 to 150 sec.					
Peak Temperature	255°C to 260°C					
Time within 5°C of Actual Peak	20 to 40 sec.					
Ramp-Down Rate	6°C/sec. max.					
Time 25°C to Peak Temperature	8 minutes max.					

7.0 PACKAGING INFORMATION

7.1 Package Marking Information

6-Lead VFLGA* (2.5mm x 2.0mm)

XXXX DCPYYWW 0SSS

6-Lead VFLGA* (1.2mm x 1.6mm) (1.6mm x 2.0mm)

XXXX SSS Example

0358 DCP1834 0K52

Example

0106 • D13

Legend: XX...X Product code or customer-specific information

Y Year code (last digit of calendar year)
YY Year code (last 2 digits of calendar year)
WW Week code (week of January 1 is week '01')

NNN Alphanumeric traceability code

(e3) Pb-free JEDEC® designator for Matte Tin (Sn)

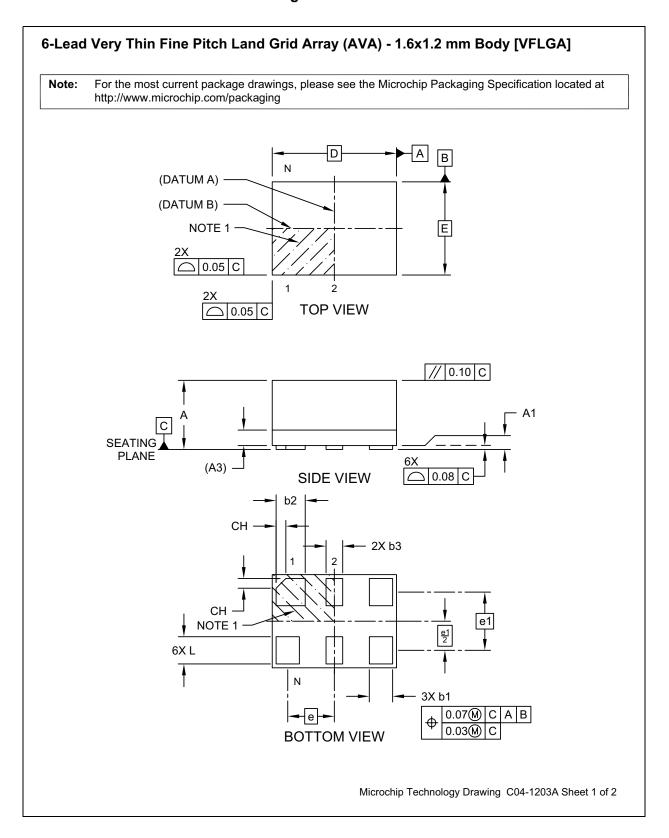
This package is Pb-free. The Pb-free JEDEC designator (e3) can be found on the outer packaging for this package.

•, ▲, ▼ Pin one index is identified by a dot, delta up, or delta down (triangle mark).

Note: In the event the full Microchip part number cannot be marked on one line, it will be carried over to the next line, thus limiting the number of available characters for customer-specific information. Package may or may not include the corporate logo.

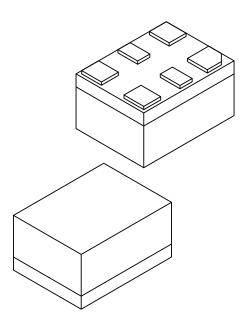
Underbar () and/or Overbar () symbol may not be to scale.

6-Lead 1.6 mm x 1.2 mm VFLGA Package Outline and Recommended Land Pattern



6-Lead Very Thin Fine Pitch Land Grid Array (AVA) - 1.6x1.2 mm Body [VFLGA]

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



	MILLIMETERS			
Dimension	Dimension Limits			MAX
Number of Terminals	Ν		6	
Terminal Pitch	е		0.60 BSC	
Terminal Pitch	e1		0.75 BSC	
Overall Height	Α	0.79	0.84	0.89
Standoff	A1	0.00	0.02	0.05
Substrate Thickness (with Terminals)	A3		0.20 REF	
Overall Length	D		1.60 BSC	
Overall Width	Е		1.20 BSC	
Terminal Width	b1	0.25	0.30	0.35
Terminal Width	b2	0.325	0.375	0.425
Terminal Width	b3	0.20	0.25	0.30
Terminal Length	Ĺ	0.30	0.35	0.40
Terminal 1 Index Chamfer	СН	-	0.125	-

Notes:

- 1. Pin 1 visual index feature may vary, but must be located within the hatched area.
- 2. Package is saw singulated
- 3. Dimensioning and tolerancing per ASME Y14.5M

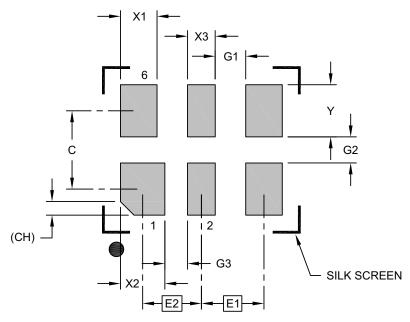
BSC: Basic Dimension. Theoretically exact value shown without tolerances.

REF: Reference Dimension, usually without tolerance, for information purposes only.

Microchip Technology Drawing C04-1203A Sheet 2 of 2

6-Lead Very Thin Fine Pitch Land Grid Array (AVA) - 1.6x1.2 mm Body [VFLGA]

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



RECOMMENDED LAND PATTERN

	Units			S
Dimension	Dimension Limits		NOM	MAX
Contact Pitch (X3)	E1		0.60 BSC	
Contact Pitch	E2		0.56 BSC	
Contact Spacing	С		0.75	
Contact Width (X3)	X1			0.35
Contact Width	X2			0.43
Contact Width (X2)	X3			0.27
Contact Pad Length (X6)	Υ			0.50
Space Between Contacts (X4)	G1	0.29		
Space Between Contacts (X3)	G2	0.25		
Space Between Contacts	G3	0.22		
Contact 1 Index Chamfer	CH	0	.13 X 45° RE	F

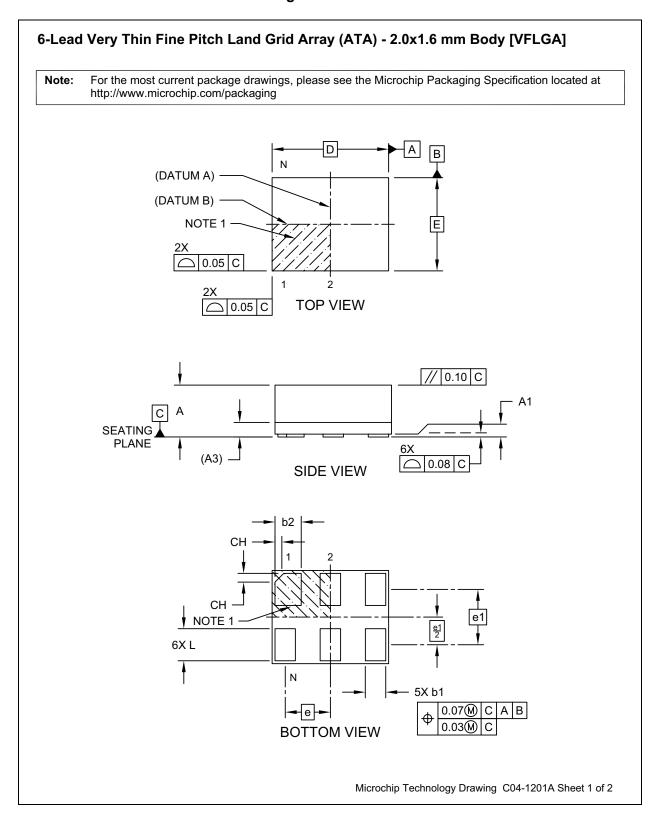
Notes:

1. Dimensioning and tolerancing per ASME Y14.5M

BSC: Basic Dimension. Theoretically exact value shown without tolerances.

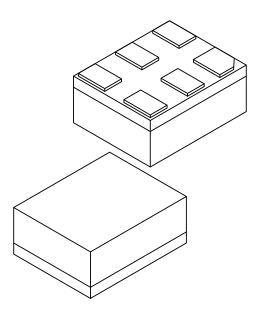
Microchip Technology Drawing C04-3203A

6-Lead 2.0 mm x 1.6 mm VFLGA Package Outline and Recommended Land Pattern



6-Lead Very Thin Fine Pitch Land Grid Array (ATA) - 2.0x1.6 mm Body [VFLGA]

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



	Units			S
Dimension	Dimension Limits			MAX
Number of Terminals	Ν		6	
Terminal Pitch	е		0.775 BSC	
Terminal Pitch	e1		0.95 BSC	
Overall Height	Α	0.79	0.84	0.89
Standoff	A1	0.00	0.02	0.05
Substrate Thickness (with Terminals)	A3		0.20 REF	
Overall Length	D		2.00 BSC	
Overall Width	Е		1.60 BSC	
Terminal Width	b1	0.30	0.35	0.40
Terminal Width	b2	0.40	0.45	0.50
Terminal Length	Г	0.50	0.55	0.60
Terminal 1 Index Chamfer	CH	-	0.15	-

Notes:

- 1. Pin 1 visual index feature may vary, but must be located within the hatched area.
- 2. Package is saw singulated
- 3. Dimensioning and tolerancing per ASME Y14.5M

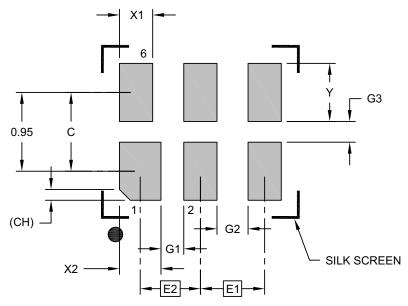
BSC: Basic Dimension. Theoretically exact value shown without tolerances.

 $\label{eq:REF:Reference Dimension, usually without tolerance, for information purposes only. \\$

Microchip Technology Drawing C04-1201A Sheet 2 of 2

6-Lead Very Thin Fine Pitch Land Grid Array (ATA) - 2.0x1.6 mm Body [VFLGA]

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



RECOMMENDED LAND PATTERN

	MILLIMETERS			
Dimension	Dimension Limits		NOM	MAX
Contact Pitch	E1		0.78 BSC	
Contact Pitch	E2		0.73 BSC	
Contact Spacing	С		0.95	
Contact Width (X4)	X1			0.40
Contact Width (X2)	X2			0.45
Contact Pad Length (X6)	Υ			0.70
Space Between Contacts (X4)	G1	0.28		
Space Between Contacts (X3)	G2	0.38		
Space Between Contacts (X3)	G3	0.25		
Contact 1 Index Chamfer	CH	0	.13 X 45° RE	F

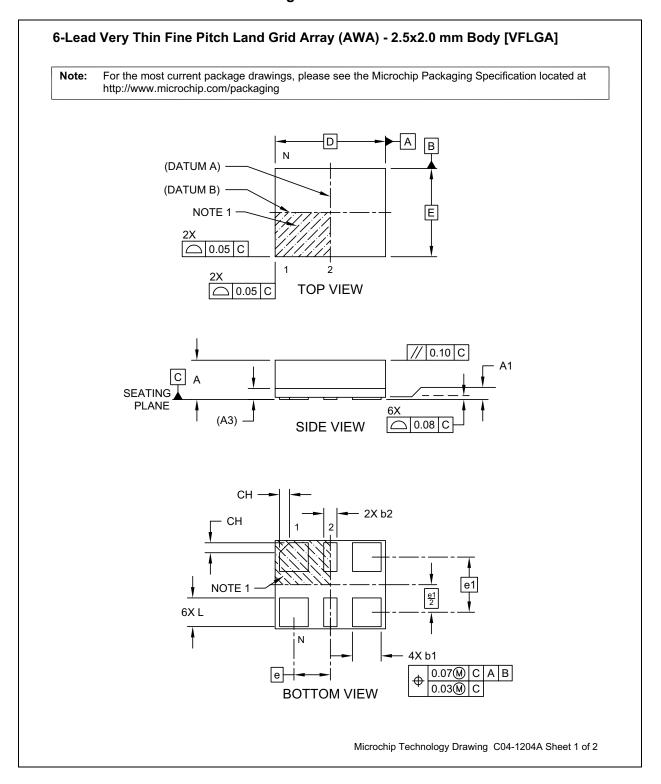
Notes:

1. Dimensioning and tolerancing per ASME Y14.5M

BSC: Basic Dimension. Theoretically exact value shown without tolerances.

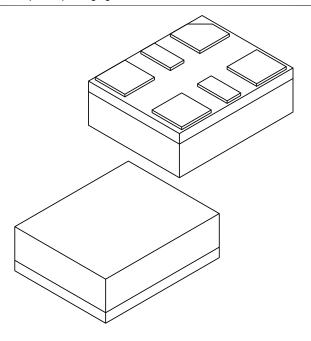
Microchip Technology Drawing C04-3201A

6-Lead 2.5 mm x 2.0 mm VFLGA Package Outline and Recommended Land Pattern



6-Lead Very Thin Fine Pitch Land Grid Array (AWA) - 2.5x2.0 mm Body [VFLGA]

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



	MILLIMETERS			
Dimension	Dimension Limits			MAX
Number of Terminals	N		6	
Terminal Pitch	е		0.825 BSC	
Terminal Pitch	e1	1.25 BSC		
Overall Height	Α	0.79	0.84	0.89
Standoff	A1	0.00	0.02	0.05
Substrate Thickness (with Terminals)	A3	0.20 REF		
Overall Length	D		2.50 BSC	
Overall Width	Е		2.00 BSC	
Terminal Width	b1	0.60	0.65	0.70
Terminal Width	b2	0.25	0.30	0.35
Terminal Length	L	0.60	0.65	0.70
Terminal 1 Index Chamfer	СН	-	0.225	-

Notes:

- 1. Pin 1 visual index feature may vary, but must be located within the hatched area.
- 2. Package is saw singulated
- 3. Dimensioning and tolerancing per ASME Y14.5M $\,$

BSC: Basic Dimension. Theoretically exact value shown without tolerances.

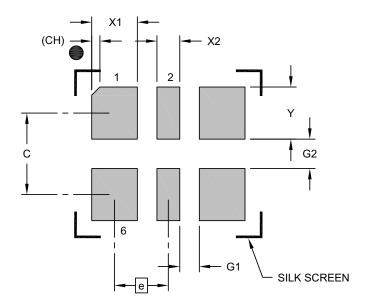
REF: Reference Dimension, usually without tolerance, for information purposes only.

Microchip Technology Drawing C04-1204A Sheet 2 of 2

Note:

6-Lead Very Thin Fine Pitch Land Grid Array (AWA) - 2.5x2.0 mm Body [VFLGA]

For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



RECOMMENDED LAND PATTERN

Units		MILLIMETERS		
Dimension Limits		MIN	NOM	MAX
Contact Pitch	Е	0.825 BSC		
Contact Spacing	С	1.25 BSC		
Contact Width (X4)	X1			0.70
Contact Width (X2)	X2			0.35
Contact Pad Length (X6)	Υ			0.80
Space Between Contacts (X4)	G1	0.30		
Space Between Contacts (X3)	G2	0.45		
Contact 1 Index Chamfer	CH	0.13 X 45° REF		

Notes:

1. Dimensioning and tolerancing per ASME Y14.5M

BSC: Basic Dimension. Theoretically exact value shown without tolerances.

Microchip Technology Drawing C04-3204A

APPENDIX A: REVISION HISTORY

Revision A (October 2018)

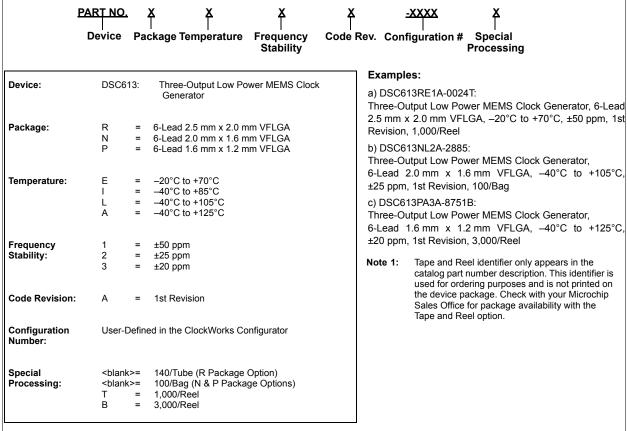
• Initial release of DSC613 as Microchip data sheet DS20006024A.

DSC613

NOTES:

PRODUCT IDENTIFICATION SYSTEM

To order or obtain information, e.g., on pricing or delivery, contact your local Microchip representative or sales office.



The DSC613 is a highly configurable device and is factory programmed to meet the customer's needs. Microchip's ClockWorks Configurator must be used to choose the necessary options, create the final part number, data sheet, and order samples.

DSC613

NOTES:

Note the following details of the code protection feature on Microchip devices:

- Microchip products meet the specification contained in their particular Microchip Data Sheet.
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